

SNLS097C - JULY 2000 - REVISED FEBRUARY 2013

DS36C280 Slew Rate Controlled CMOS EIA-RS-485 Transceiver

Check for Samples: DS36C280

FEATURES

- 100% RS-485 Compliant
 - Guaranteed RS-485 Device Interoperation
- Low Power CMOS Design: I_{cc} 500 μA max
- Adjustable Slew Rate Control
 Minimizes EMI Effects
- Built-In Power Up/Down Glitch-Free Circuitry
 - Permits Live Transceiver Insertion/Displacement
- SOIC Packages
- Industrial Temperature Range: -40°C to +85°C
- On-board Thermal Shutdown Circuitry
 - Prevents Damage to the Device in the Event of Excessive Power Dissipation
- Wide Common Mode Range: -7V to +12V
- Receiver Open Input Fail-safe (1)
- ¼ unit load (DS36C280): ≥128 nodes
- 1⁄₂ unit load (DS36C280T): ≥64 nodes
- ESD (human body model): ≥2 kV
- (1) Non-terminated, Open Inputs only

Connection and Logic Diagram

DESCRIPTION

The DS36C280 is a low power differential bus/line transceiver designed to meet the requirements of RS-485 Standard for multipoint data transmission. In addition, it is compatible with TIA/EIA-422-B.

The slew rate control feature allows the user to set the driver rise and fall times by using an external resistor. Controlled edge rates can reduce switching EMI.

The CMOS design offers significant power savings over its bipolar and ALS counterparts without sacrificing ruggedness against ESD damage. The device is ideal for use in battery powered or power conscious applications. I_{CC} is specified at 500 μ A maximum.

The driver and receiver outputs feature TRI-STATE capability. The driver outputs operate over the entire common mode range of -7V to +12V. Bus contention or fault situations are handled by a thermal shutdown circuit, which forces the driver outputs into the high impedance state.

The receiver incorporates a fail safe circuit which guarantees a high output state when the inputs are left open $^{(1)}$.

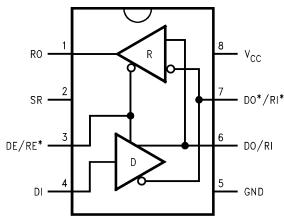


Figure 1. See Package Number D (R-PDSO-G8)

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. All trademarks are the property of their respective owners.

ISTRUMENTS

EXAS

Truth Table⁽¹⁾

DRIVER SECTION			
DE/RE*	DI	DO/RI	DO*/RI*
Н	Н	Н	L
Н	L	L	Н
L	Х	Z	Z
RECEIVER SECTION			
DE/RE*		RI-RI*	RO
L		≥+0.2V	Н
L		≤-0.2V	L
Н		Х	Z
L		OPEN ⁽¹⁾	Н

(1) Non-terminated, Open Inputs only



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings⁽¹⁾⁽²⁾

Supply Voltage (V _{CC})	+12V
Input Voltage (DE/RE*, & DI)	-0.5V to (V _{CC} +0.5V)
Common Mode (V _{CM})	
Driver Output/Receiver Input	±15V
Input Voltage (DO/RI, DO*/RI*)	±14V
Receiver Output Voltage	-0.5V to (V _{CC} +0.5V)
Maximum Package Power Dissipation @ +25°C	
M Package 1190 mV, derate	9.5 mW/°C above +25°C
Storage Temperature Range	−65°C to +150°C
Lead Temperature	+260°C
(Soldering 4 sec.)	

(1) "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" specifies conditions of device operation.

(2) If Military/Aerospace specified devices are required, please contact the TI Sales Office/Distributors for availability and specifications.

Recommended Operating Conditions

	Min	Тур	Max	Units
Supply Voltage (V _{CC})	+4.75	+5.0	+5.25	V
Bus Voltage	-7		+12	V
Operating Free Air Temperature (T _A)				
DS36C280T	-40	+25	+85	°C
DS36C280	0	+25	+70	°C

Electrical Characteristics⁽¹⁾⁽²⁾

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified

Symbol	Parameter	Conditio	ons	Ref	erence	Min	Тур	Max	Units
DIFFERE	NTIAL DRIVER CHARACTERIS	TICS							
V _{OD1}	Differential Output Voltage	I _O = 0 mA (No Load)				1.5		5.0	V
V _{OD0}	Output Voltage	I _O = 0 mA		422) 485)	0		5.0	V	
V _{OD0*}	Output Voltage	(Output to GND)			+00)	0		5.0	V
V _{OD2}	Differential Output Voltage	$R_L = 50\Omega$	(422)	Figure 2	2.0	2.8		V	
	(Termination Load)	$R_L = 27\Omega$		(485)		1.5	2.3	5.0	V
ΔV_{OD2}	Balance of V _{OD2}	$R_L = 27\Omega \text{ or } 50\Omega$			(3)		0.4		
	V _{OD2} - V _{OD2*}			(42)	2, 485)	-0.2	0.1	+0.2	V
V _{OD3}	Differential Output Voltage	R1 = 54Ω, R2 = 375Ω		Fig	gure 3	1.5	2.0	5.0	V
	(Full Load)	$V_{\text{TEST}} = -7V$ to +12V							
V _{oc}	Driver Common Mode	$R_L = 27\Omega$		(485)	Figure 2	0		3.0	V
	Output Voltage	$R_L = 50\Omega$	(422)		0		3.0	V	
ΔV _{OC}	Balance of V _{OC}	$R_L = 27\Omega$ or			(3)				
	V _{OC} - V _{OC*}	$R_L = 50\Omega$				-0.2		+0.2	V
I _{OSD} Driver Output Short-Circuit		V _O = +12V	(•	485)		200	+250	mA	
	Current	V _O = -7V		(4	485)		-190	-250	mA
RECEIVE	ER CHARACTERISTICS						•		
V _{TH} Differential Input High Threshold Voltage		$V_{O} = V_{OH}, I_{O} = -0.4 \text{ m}$				0.005			
		$-7V \le V_{CM} \le +12V$		_	(4)		+0.035	+0.2	V
V _{TL}	Differential Input Low	$V_{O} = V_{OL}, I_{O} = 0.4 \text{ mA}$	(42)	2, 485)		0.005			
	Threshold Voltage	$-7V \le V_{CM} \le +12V$			-0.2	-0.035		V	
V _{HST}	Hysteresis ⁽⁵⁾	$V_{CM} = 0V$					70		mV
R _{IN}	Input Resistance	$-7V \le V_{CM} \le +12V$		DS3	6C280T	24	68		kΩ
R _{IN}	Input Resistance	$-7V \le V_{CM} \le +12V$		DS3	6C280	48	68		kΩ
I _{IN}	Line Input Current	Other Input = 0V	DS36C280	V _{IN} = +12	2V	0	0.19	0.25	mA
	(6)	$DE = V_{IL}, RE^* = V_{IL}$		$V_{IN} = -7$	V	0	-0.1	-0.2	mA
		V _{CC} = 4.75 to 5.25	DS36C280T	V _{IN} = +12	2V	0	0.19	0.5	mA
		or 0V		$V_{IN} = -7$	V	0	-0.1	-0.4	mA
I _{ING}	Line Input Current	Other Input = 0V	DS36C280	V _{IN} = +12	2V	0	0.19	0.25	mA
	Glitch ⁽⁶⁾	$DE = V_{IL}, RE^* = V_{IL}$		$V_{IN} = -7$	V	0	-0.1	-0.2	mA
		V _{CC} = +3.0V	DS36C280T	V _{IN} = +12	2V	0	0.19	0.5	mA
		or 0V $T_A = 25^{\circ}C$		$V_{IN} = -7$	V	0	-0.1	-0.4	mA
I _B	Input Balance Test	RS = 500Ω		22) (7)			±400	mV	
V _{OH}	High Level Output Voltage	$I_{OH} = -4 \text{ mA}, V_{ID} = +0$.2V		RO	3.5	4.6		V
V _{OL}	Low Level Output Voltage	$I_{OL} = +4 \text{ mA}, V_{ID} = -0$	Fig	ure 12		0.3	0.5	V	
I _{OSR}	Short Circuit Current	V _O = GND			RO	7	35	85	mA
I _{OZR}	TRI-STATE Leakage Current	$V_0 = 0.4V$ to 2.4V					±1	μA	
	CHARACTERISTICS			-1			1	1	

(1) Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground except V_{OD1} and V_{OD2}.

(2)

- All typicals are given for: $V_{CC} = +5.0V$, $T_A = +25^{\circ}C$. Delta $|V_{OD2}|$ and Delta $|V_{OC}|$ are changes in magnitude of V_{OD2} and V_{OC} , respectively, that occur when input changes state. (3)
- Threshold parameter limits specified as an algebraic value rather than by magnitude. Hysteresis defined as $V_{HST} = V_{TH} V_{TL}$. (4)
- (5)
- I_{IN} includes the receiver input current and driver TRI-STATE leakage current. (6)
- For complete details of test, see RS-485. (7)

EXAS STRUMENTS

www.ti.com

Electrical Characteristics⁽¹⁾⁽²⁾ (continued)

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified

Symbol	Parameter	Condition	Conditions			Тур	Max	Units
V _{IH}	High Level Input Voltage				2.0		V _{CC}	V
V _{IL}	Low Level Input Voltage						0.8	V
I _{IH}	High Level Input Current	$V_{IH} = V_{CC}$	DE/RE*, DI			2	μA	
IIL	Low Level Input Current	$V_{CC} = 5.0V$	N/ 0)/				-2	μA
		$V_{CC} = +3.0V$	$V_{IL} = 0V$				-2	μA
		SR = 0V	SR = 0V				-1	mA
I _{CCR}	Power Supply Current	Driver OFF, Receiver C	N	V _{CC}		200	500	μA
I _{CCD}	(No Load)	Driver ON, Receiver OF	Driver ON, Receiver OFF			200	500	μA

Switching Characteristics⁽¹⁾⁽²⁾⁽³⁾

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified

Symbol	Parameter	Conditions	Reference	Min	Тур	Max	Units
DRIVER C	HARACTERISTICS					•	•
t _{PHLD}	Differential Propagation Delay High to Low	$R_L = 54\Omega, C_L = 100 \text{ pF}$	Figure 6, Figure 7	10	399	1000	ns
t _{PLHD}	Differential Propagation Delay Low to High			10	400	1000	ns
t _{SKD}	Differential Skew			0	4	10	
	t _{PHLD} - t _{PLHD}			0	1	10	ns
t _r	Rise Time	SR = Open			2870		ns
t _f	Fall Time				3070		ns
t _r	Rise Time	SR = 100 kΩ			1590		ns
t _f	Fall Time				1640		ns
t _r	Rise Time	SR = Short		100	337	1000	ns
t _f	Fall Time			100	348	1000	ns
t _{PHZ}	Disable Time High to Z	C _L = 15 pF	Figure 8, Figure 9		1100	2000	ns
t _{PLZ}	Disable Time Low to Z		Figure 10, Figure 11		500	800	ns
t _{PZH}	Enable Time Z to High	C _L = 100 pF	Figure 8, Figure 9		300	500	ns
t _{PZL}	Enable Time Z to Low		Figure 10, Figure 11		300	500	ns
RECEIVER	CHARACTERISTICS						
t _{PHL}	Propagation Delay High to Low	C _L = 15 pF		30	210	400	ns
t _{PLH}	Propagation Delay Low to High		Figure 13, Figure 14	30	190	400	ns
t _{SK}	Skew, t _{PHL} - t _{PLH}			0	20	50	ns
t _{PLZ}	Output Disable Time	C _L = 15 pF			50	150	ns
t _{PHZ}			Figure 15, Figure 16,		55	150	ns
t _{PZL}	Output Enable Time		Figure 17		40	150	ns
t _{PZH}					45	150	ns

All typicals are given for: V_{CC} = +5.0V, T_A = + 25°C.
 C_L includes probe and jig capacitance.
 SR = GND for all Switching Characteristics unless otherwise specified.



Product Folder Links: DS36C280

1.5V

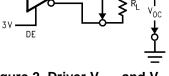
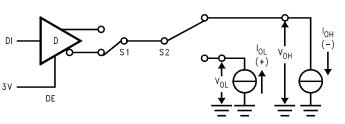


Figure 2. Driver V_{OD2} and V_{OC}



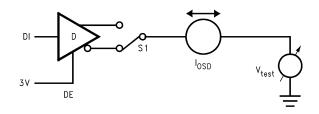
PARAMETER MEASUREMENT INFORMATION

DI

3١

DF

Figure 4. Driver V_{OH} and V_{OL}



Vtest = -7V to +12V

Figure 5. Driver I_{OSD}

DI

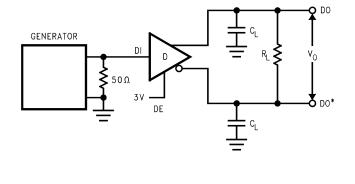
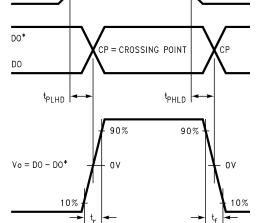


Figure 6. Driver Differential Propagation Delay Test

Circuit





1.5V



V_{test} =

-7V to +12V

R2

R2

R 1

Figure 3. Driver V_{OD3}

DI

DS36C280



SNLS097C-JULY 2000-REVISED FEBRUARY 2013

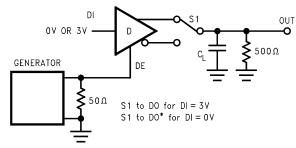


Figure 8. TRI-STATE Test Circuit (t_{PZH} , t_{PHZ})

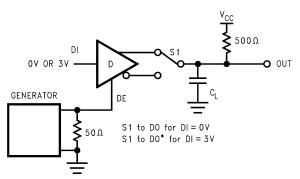


Figure 10. TRI-STATE Test Circuit (t_{PZL}, t_{PLZ})

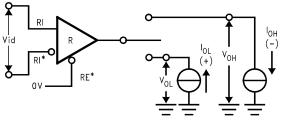


Figure 12. Receiver V_{OH} and V_{OL}

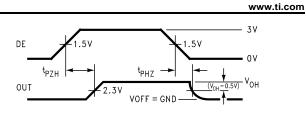
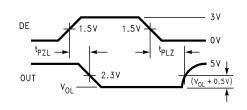


Figure 9. TRI-STATE Waveforms (t_{PZH}, t_{PHZ})





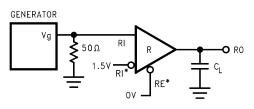


Figure 13. Receiver Differential Propagation Delay Test Circuit

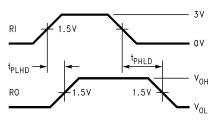


Figure 14. Receiver Differential Propagation Delay Waveforms



SNLS097C – JULY 2000 – REVISED FEBRUARY 2013

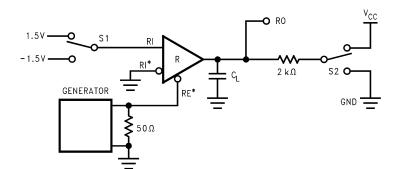


Figure 15. Receiver TRI-STATE Test Circuit

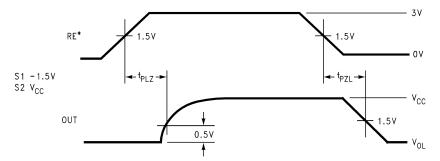


Figure 16. Receiver Enable and Disable Waveforms (t_{PLZ}, t_{PZL})

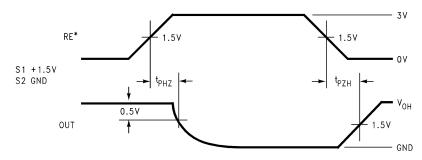


Figure 17. Receiver Enable and Disable Waveforms (t_{PHZ} , t_{PZH})

Typical Application Information

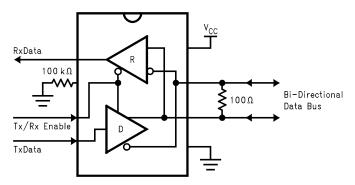


Figure 18. Typical Pin Connection

SNLS097C – JULY 2000 – REVISED FEBRUARY 2013

Pin #	Name	Description
1	RO	Receiver Output: When DE/RE* (Receiver Enable) is LOW, the receiver is enabled (ON), if DO/RI \geq DO*/RI* by 200 mV, RO will be HIGH. If DO/RI \leq DO*/RI* by 200 mV, RO will be LOW. Additionally RO will be HIGH for OPEN (Non-terminated) inputs.
2	SR	Slew Rate Control: A resistor connected to Ground controls the Driver Output rising and falling edge rates.
3	DE/RE*	Combined Driver and Receiver Output Enable: When signal is LOW the receiver output is enabled and the driver outputs are in TRI-STATE (OFF). When signal is HIGH, the receiver output is in TRI-STATE (OFF) and the driver outputs are enabled.
4	DI	Driver Input: When DE/RE* is HIGH, the driver is enabled, if DI is LOW, then DO/RI will be LOW and DO*/RI* will be HIGH. If DI is HIGH, then DO/RI is HIGH and DO*/RI* is LOW.
5	GND	Ground Connection
6	DO/RI	Driver Output/Receiver Input, 485 Bus Pin.
7	DO*/RI*	Driver Output/Receiver Input, 485 Bus Pin.
8	V _{CC}	Positive Power Supply Connection: Recommended operating range for V _{CC} is +4.75V to +5.25V.

Table 1. DEVICE PIN DESCRIPTIONS

Unit Load

A unit load for a RS-485 receiver is defined by the input current versus the input voltage curve. The gray shaded region is the defined operating range from -7V to +12V. The top border extending from -3V at 0 mA to +12V at +1 mA is defined as one unit load. Likewise, the bottom border extending from +5V at 0 mA to -7V at -0.8 mA is also defined as one unit load (see Figure 19). A RS-485 driver is capable of driving up to 32 unit loads. This allows upto 32 nodes on a single bus. Although sufficient for many applications, it is sometime desirable to have even more nodes. For example an aircraft that has 32 rows with 4 seats per row could benefit from having 128 nodes on one bus. This would allow signals to be transferred to and from each individual seat to 1 main station. Usually there is one or two less seats in the last row of the aircraft near the restrooms and food storage area. This frees the node for the main station.

The DS36C278, the DS36C279, and the DS36C280 all have ½ unit load and ¼ unit load (UL) options available. These devices will allow upto 64 nodes or 128 nodes guaranteed over temperature depending upon which option is selected. The ½ UL option is available in industrial temperature and the ¼ UL is available in commercial temperature.

First, for a $\frac{1}{2}$ UL device the top and bottom borders shown in Figure 19 are scaled. Both 0 mA reference points at +5V and -3V stay the same. The other reference points are +12V at +0.5 mA for the top border and -7V at -0.4 mA for the bottom border (see Figure 19). Second, for a $\frac{1}{4}$ UL device the top and bottom borders shown in Figure 19 are scaled also. Again, both 0 mA reference points at +5V and -3V stay the same. The other reference points at +5V and -3V stay the same. The other reference points are +12V at +0.25 mA for the top border and -7V at -0.2 mA for the bottom border (see Figure 19).

The advantage of the ½ UL and ¼ UL devices is the increased number of nodes on one bus. In a single master multi-slave type of application were the number of slaves exceeds 32, the DS36C278/279/280 may save in the cost of extra devices like repeaters, extra media like cable, and/or extra components like resistors.

The DS36C279 and DS36C280 have addition feature which offer more advantages. The DS36C279 has an automatic sleep mode function for power conscious applications. The DS36C280 has a slew rate control for EMI conscious applications. Refer to the sleep mode and slew rate control portion of the application information section in the corresponding datasheet for more information on these features.

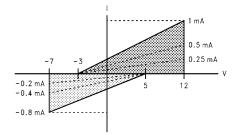


Figure 19. Input Current vs Input Voltage Operating Range

FXAS

NSTRUMENTS

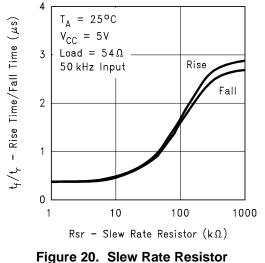
www.ti.com



Slew Rate Control

The DS36C280 features an adjustable slew rate control. This feature allows more control over EMI levels than tradition fixed edge rate devices. The slew rate control may be adjusted with or without any external components. The DS36C280 offers both low power (I_{CC} 500 µA max) and low EMI for an RS-485 interface.

The slew rate control is located at pin two of the device and only controls the driver output edges. The slew rate control pin (SR) may be left open or shorted to ground, with or without a resistor. When the SR pin is shorted to ground without a resistor, the driver output edges will transition typically 350 ns. When the SR pin is left open, the driver output edges will transition typically 3 μ s. When the SR pin is shorted to ground with a resistor, the driver output edges will transition between 350 ns and 3 μ s depending on the resistor value. Refer to the slew rate versus resistor value curve in this datasheet for determining resistor values and expected typical slew rate value. Please note, when slowing the edge rates of the device will decrease the maximum data rate also.



vs Differential Rise/Rise/Fall Time

SNLS097C – JULY 2000-REVISED FEBRUARY 2013

10 Submit Documentation Feedback

Copyright © 2000–2013, Texas Instruments Incorporated

REVISION HISTORY

Cł	nanges from Revision B (February 2013) to Revision C P	age
•	Changed layout of National Data Sheet to TI format	9

NSTRUMENTS

www.ti.com

EXAS

Page



PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
DS36C280M/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	0 to 70	36C28 0M	Samples
DS36C280MX	ACTIVE	SOIC	D	8	2500	TBD	Call TI	Call TI	0 to 70	36C28 0M	Samples
DS36C280MX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	0 to 70	36C28 0M	Samples
DS36C280TM	ACTIVE	SOIC	D	8	95	TBD	Call TI	Call TI	0 to 70	36C28 0TM	Samples
DS36C280TM/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	0 to 70	36C28 0TM	Samples
DS36C280TMX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	0 to 70	36C28 0TM	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.



11-Apr-2013

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com

Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DS36C280MX	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
DS36C280MX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
DS36C280TMX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

TEXAS INSTRUMENTS

www.ti.com

PACKAGE MATERIALS INFORMATION

21-Feb-2013



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DS36C280MX	SOIC	D	8	2500	349.0	337.0	45.0
DS36C280MX/NOPB	SOIC	D	8	2500	349.0	337.0	45.0
DS36C280TMX/NOPB	SOIC	D	8	2500	349.0	337.0	45.0

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products		Applications	
Audio	www.ti.com/audio	Automotive and Transportation	www.ti.com/automotive
Amplifiers	amplifier.ti.com	Communications and Telecom	www.ti.com/communications
Data Converters	dataconverter.ti.com	Computers and Peripherals	www.ti.com/computers
DLP® Products	www.dlp.com	Consumer Electronics	www.ti.com/consumer-apps
DSP	dsp.ti.com	Energy and Lighting	www.ti.com/energy
Clocks and Timers	www.ti.com/clocks	Industrial	www.ti.com/industrial
Interface	interface.ti.com	Medical	www.ti.com/medical
Logic	logic.ti.com	Security	www.ti.com/security
Power Mgmt	power.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video
RFID	www.ti-rfid.com		
OMAP Applications Processors	www.ti.com/omap	TI E2E Community	e2e.ti.com
Wireless Connectivity	www.ti.com/wirelessconne	ectivity	

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2013, Texas Instruments Incorporated